



# THE DATASHEET OF ESD8704MUTAG



# ESD Protection Diode

## Low Capacitance Array for High Speed Data Lines

### ESD8704

The ESD8704 is designed to protect high speed data lines from ESD. Ultra-low capacitance and low ESD clamping voltage make this device an ideal solution for protecting voltage sensitive high speed data lines. The flow-through style package allows for easy PCB layout and matched trace lengths necessary to maintain consistent impedance between high speed differential lines such as USB 3.0/3.1.

#### Features

- Low Capacitance (0.5 pF Max, I/O to GND)
- Protection for the Following IEC Standards:  
IEC 61000-4-2 (Level 4)
- Low ESD Clamping Voltage
- SZESD8704MTWTAG – Wettable Flank Package for optimal Automated Optical Inspection (AOI)
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### Typical Applications

- USB 3.0/3.1
- eSATA
- DisplayPort

#### MAXIMUM RATINGS (T<sub>J</sub> = 25°C unless otherwise noted)

| Rating   | Symbol           | Value       | Unit |
|--|------------------|-------------|------|
| Operating Junction Temperature Range           | T <sub>J</sub>   | -55 to +125 | °C   |
| Storage Temperature Range                      | T <sub>stg</sub> | -55 to +150 | °C   |
| Lead Solder Temperature – Maximum (10 Seconds) | T <sub>L</sub>   | 260         | °C   |
| IEC 61000-4-2 Contact (ESD)                    | ESD              | ±30         | kV   |
| IEC 61000-4-2 Air (ESD)                        | ESD              | ±30         | kV   |

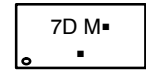
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

See Application Note AND8308/D for further description of survivability specs.

#### MARKING DIAGRAM



UDFN10  
CASE 517BB



7D = Specific Device Code  
M = Date Code  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

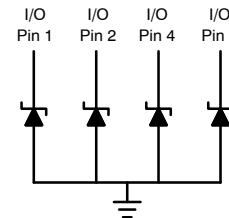
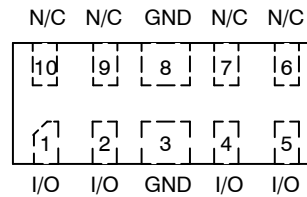


WDFNW10  
CASE 515AH



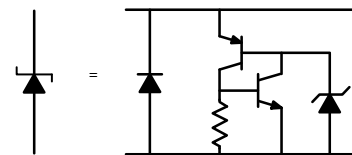
AAA = Specific Device Code  
M = Date Code

#### PIN CONFIGURATION AND SCHEMATIC



Pins 3, 8

Note: Common GND – Only Minimum of 1 GND connection required



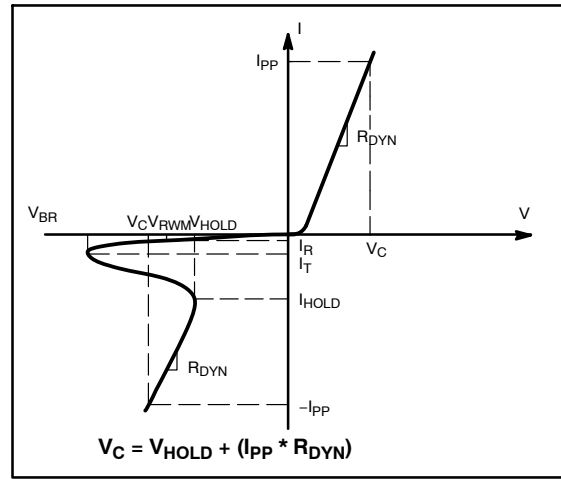
#### ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 8 of this data sheet.

**ELECTRICAL CHARACTERISTICS**

(T<sub>A</sub> = 25°C unless otherwise noted)

| Symbol            | Parameter  |
|-------------------|--|
| V <sub>RWM</sub>  | Working Peak Voltage   |
| I <sub>R</sub>    | Maximum Reverse Leakage Current @ V <sub>RWM</sub>   |
| V <sub>BR</sub>   | Breakdown Voltage @ I <sub>T</sub>   |
| I <sub>T</sub>    | Test Current   |
| V <sub>HOLD</sub> | Holding Reverse Voltage  |
| I <sub>HOLD</sub> | Holding Reverse Current  |
| R <sub>DYN</sub>  | Dynamic Resistance   |
| I <sub>PP</sub>   | Maximum Peak Pulse Current   |
| V <sub>C</sub>    | Clamping Voltage @ I <sub>PP</sub><br>V <sub>C</sub> = V <sub>HOLD</sub> + (I <sub>PP</sub> * R <sub>DYN</sub> ) |



**ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise specified)

| Parameter               | Symbol            | Conditions  | Min | Typ                            | Max                          | Unit |
|-------------------------|-------------------|---|-----|--------------------------------|------------------------------|------|
| Reverse Working Voltage | V <sub>RWM</sub>  | I/O Pin to GND  |     |                                | 3.3                          | V    |
| Breakdown Voltage       | V <sub>BR</sub>   | I <sub>T</sub> = 1 mA, I/O Pin to GND   |     | 5.0                            | 6.0                          | V    |
| Reverse Leakage Current | I <sub>R</sub>    | V <sub>RWM</sub> = 3.3 V, I/O Pin to GND  |     |                                | 1.0                          | μA   |
| Holding Reverse Voltage | V <sub>HOLD</sub> | I/O Pin to GND  |     | 1.9                            |                              | V    |
| Holding Reverse Current | I <sub>HOLD</sub> | I/O Pin to GND  |     | 20                             |                              | mA   |
| Clamping Voltage        | V <sub>C</sub>    | IEC61000-4-2, ±8 kV Contact   |     |                                |                              | V    |
| Clamping Voltage TLP    | V <sub>C</sub>    | I <sub>PP</sub> = 8 A<br>I <sub>PP</sub> = -8 A<br><br>I <sub>PP</sub> = 16 A<br>I <sub>PP</sub> = -16 A  |     | 4.7<br>-4.0<br><br>6.6<br>-6.7 |                              | V    |
| Dynamic Resistance      | R <sub>DYN</sub>  | I/O Pin to GND<br>GND to I/O Pin  |     | 0.30<br>0.38                   |                              | Ω    |
| Junction Capacitance    | C <sub>J</sub>    | V <sub>R</sub> = 0 V, f = 1 MHz between I/O Pins and GND<br>V <sub>R</sub> = 0 V, f = 2.5 GHz between I/O Pins and GND<br>V <sub>R</sub> = 0 V, f = 5.0 GHz between I/O Pins and GND<br>V <sub>R</sub> = 0 V, f = 1 MHz, between I/O Pins |     | 0.30<br>0.30<br>0.31<br>0.15   | 0.50<br>0.40<br>0.40<br>0.25 | pF   |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

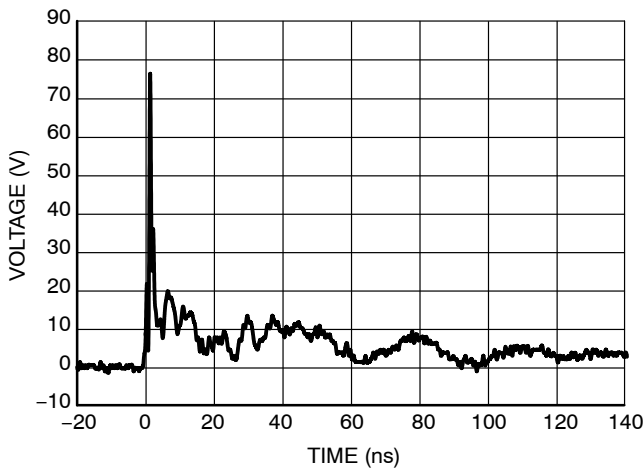


Figure 1. IEC61000-4-2 +8 kV Contact Clamping Voltage

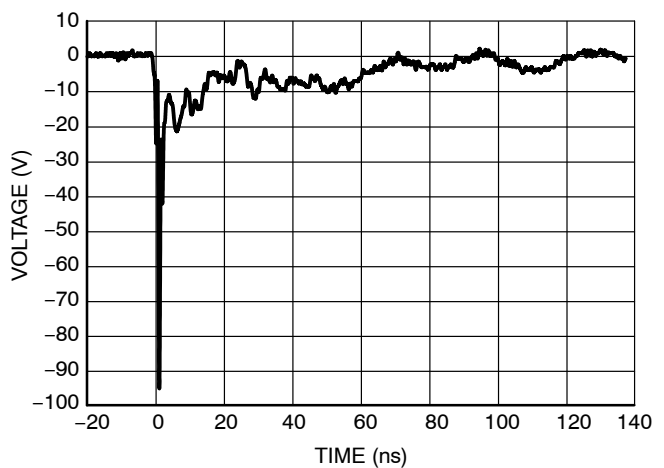


Figure 2. IEC61000-4-2 -8 kV Contact Clamping Voltage

# ESD8704

## IEC 61000-4-2 Spec.

| Level | Test Voltage (kV) | First Peak Current (A) | Current at 30 ns (A) | Current at 60 ns (A) |
|-------|-------------------|------------------------|----------------------|----------------------|
| 1     | 2                 | 7.5                    | 4                    | 2                    |
| 2     | 4                 | 15                     | 8                    | 4                    |
| 3     | 6                 | 22.5                   | 12                   | 6                    |
| 4     | 8                 | 30                     | 16                   | 8                    |



Figure 3. IEC61000-4-2 Spec

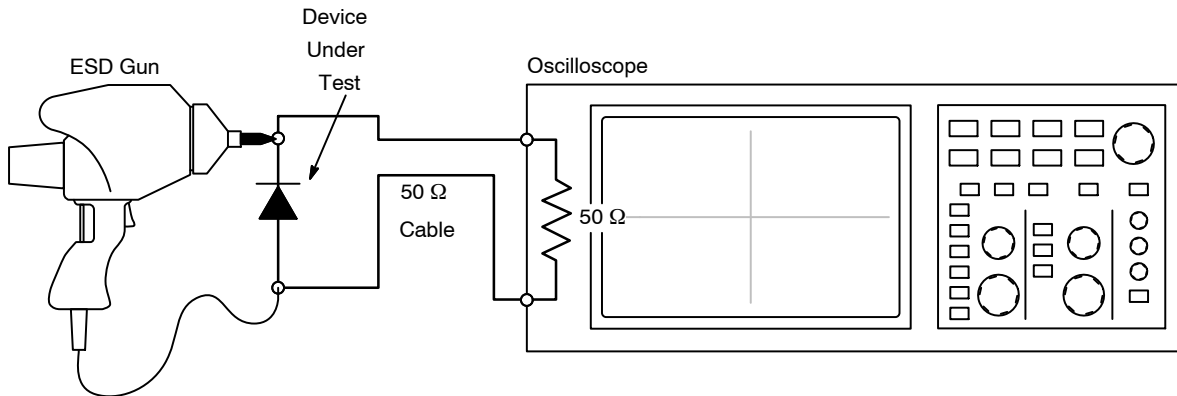


Figure 4. Diagram of ESD Clamping Voltage Test Setup

The following is taken from Application Note AND8307/D – Characterization of ESD Clamping Performance.

### ESD Voltage Clamping

For sensitive circuit elements it is important to limit the voltage that an IC will be exposed to during an ESD event to as low a voltage as possible. The ESD clamping voltage is the voltage drop across the ESD protection diode during an ESD event per the IEC61000-4-2 waveform. Since the IEC61000-4-2 was written as a pass/fail spec for larger

systems such as cell phones or laptop computers it is not clearly defined in the spec how to specify a clamping voltage at the device level. **onsemi** has developed a way to examine the entire voltage waveform across the ESD protection diode over the time domain of an ESD pulse in the form of an oscilloscope screenshot, which can be found on the datasheets for all ESD protection diodes. For more information on how **onsemi** creates these screenshots and how to interpret them please refer to AND8307/D.

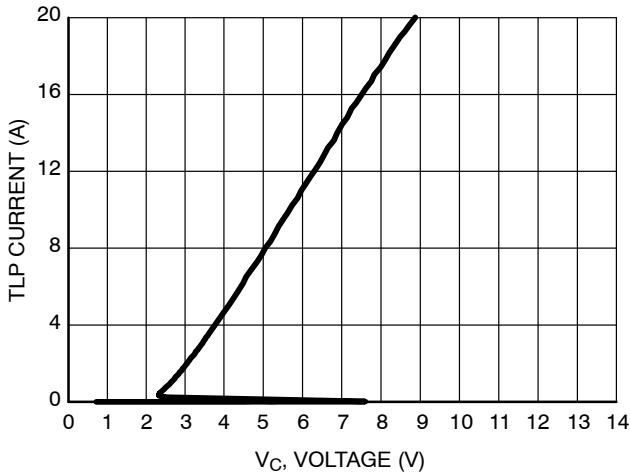


Figure 5. Positive TLP I-V Curve

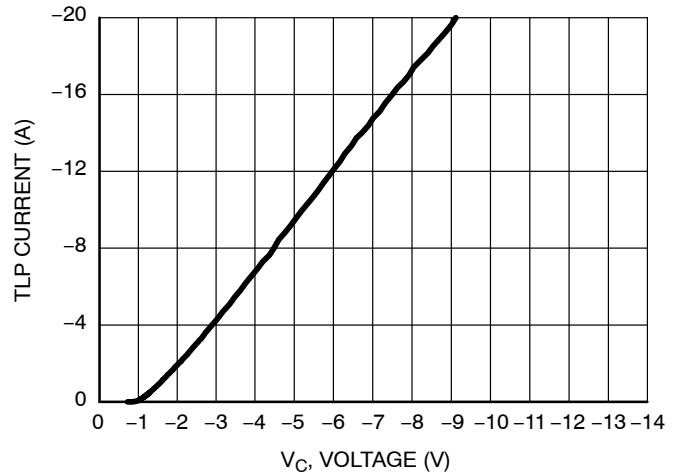


Figure 6. Negative TLP I-V Curve

NOTE: TLP parameter:  $Z_0 = 50 \Omega$ ,  $t_p = 100 \text{ ns}$ ,  $t_r = 300 \text{ ps}$ , averaging window:  $t_1 = 30 \text{ ns}$  to  $t_2 = 60 \text{ ns}$ .  $V_{IEC}$  is the equivalent voltage stress level calculated at the secondary peak of the IEC 61000-4-2 waveform at  $t = 30 \text{ ns}$  with  $2 \text{ A/kV}$ . See TLP description below for more information.

**Transmission Line Pulse (TLP) Measurement**

Transmission Line Pulse (TLP) provides current versus voltage (I-V) curves in which each data point is obtained from a 100 ns long rectangular pulse from a charged transmission line. A simplified schematic of a typical TLP system is shown in Figure 7. TLP I-V curves of ESD protection devices accurately demonstrate the product’s ESD capability because the 10s of amps current levels and under 100 ns time scale match those of an ESD event. This is illustrated in Figure 8 where an 8 kV IEC 61000-4-2 current waveform is compared with TLP current pulses at 8 A and 16 A. A TLP I-V curve shows the voltage at which the device turns on as well as how well the device clamps voltage over a range of current levels. For more information on TLP measurements and how to interpret them please refer to AND9007/D.

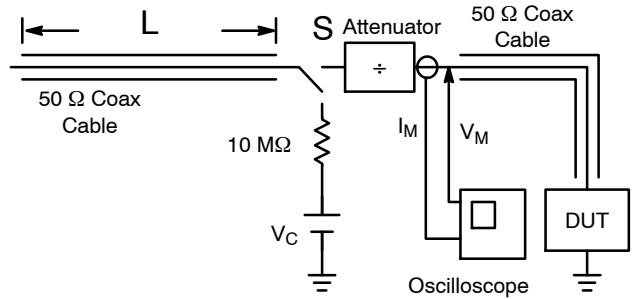


Figure 7. Simplified Schematic of a Typical TLP System

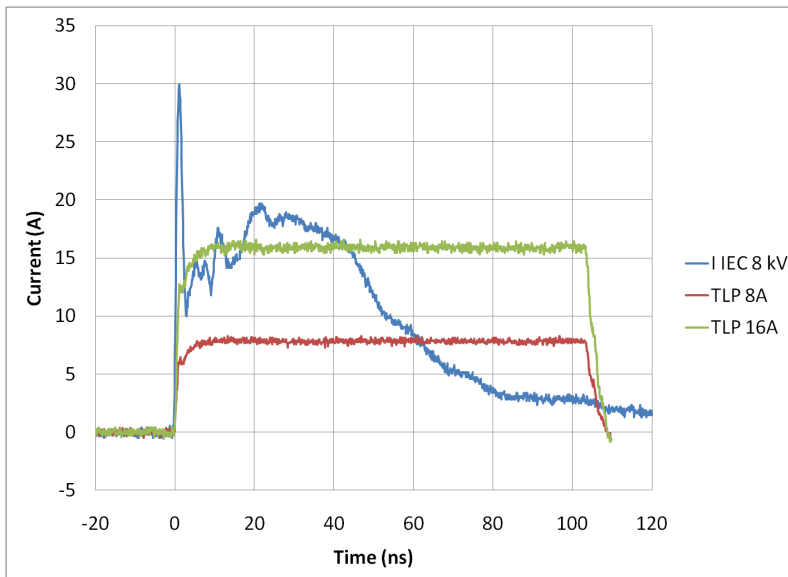
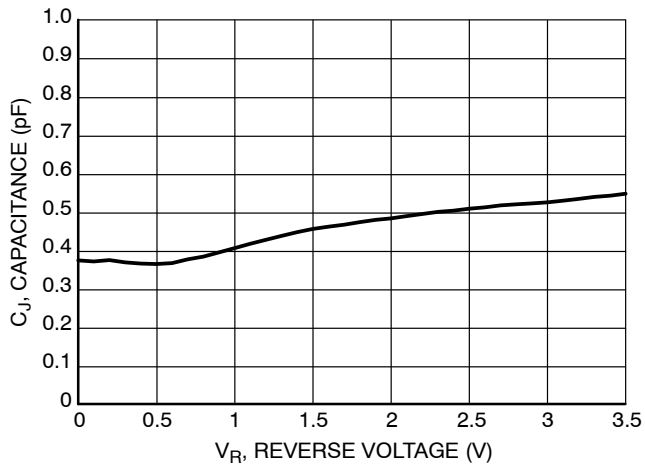
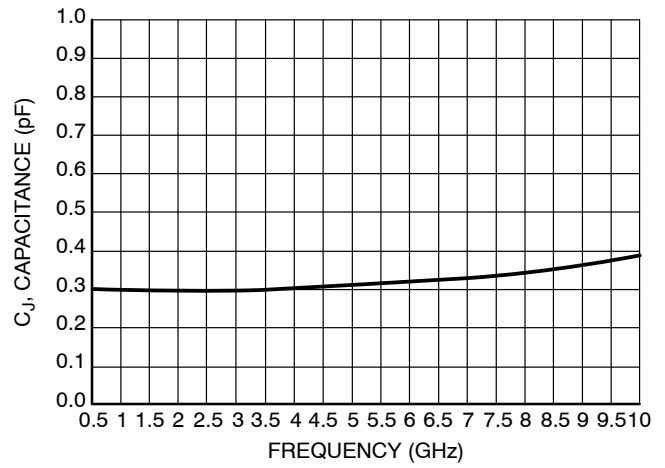


Figure 8. Comparison Between 8 kV IEC 61000-4-2 and 8 A and 16 A TLP Waveforms

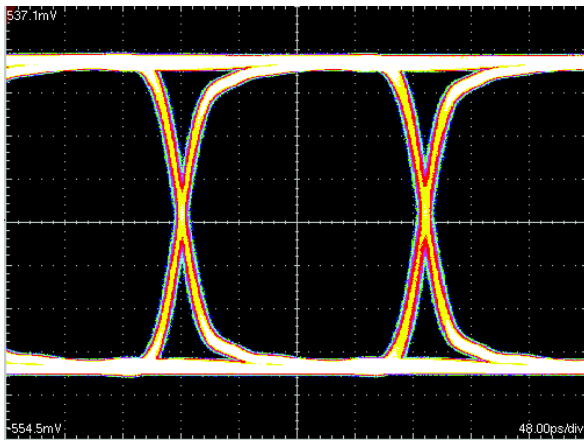
# ESD8704



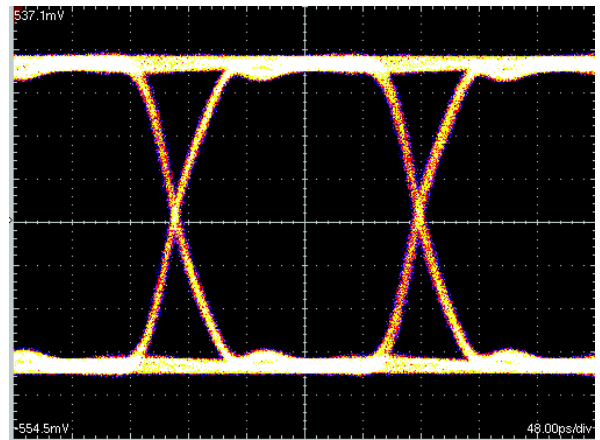
**Figure 9. Junction Capacitance vs. Reverse Voltage**



**Figure 10. Junction Capacitance vs. Frequency**

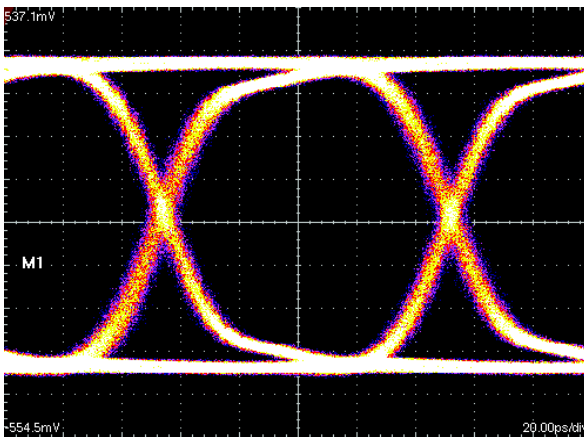


5 Gbps Eye Diagram Without ESD8704

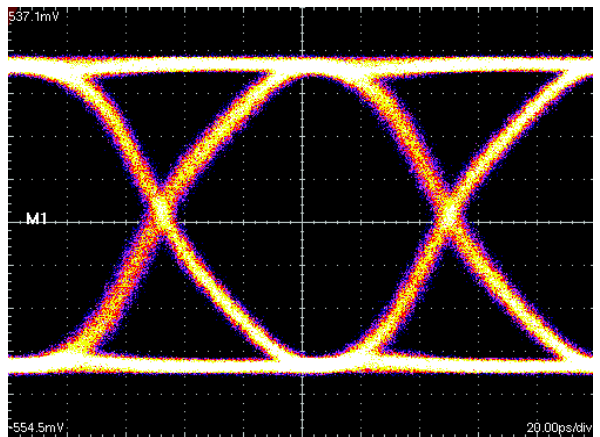


5 Gbps Eye Diagram With ESD8704

**Figure 11. USB3.0 Eye Diagram with and without ESD8704. 5 Gb/s**



10 Gbps Eye Diagram Without ESD8704



10 Gbps Eye Diagram With ESD8704

**Figure 12. USB3.1 Eye Diagram with and without ESD8704. 10 Gb/s**

See application note AND9075/D for further description of eye diagram testing methodology.

# ESD8704

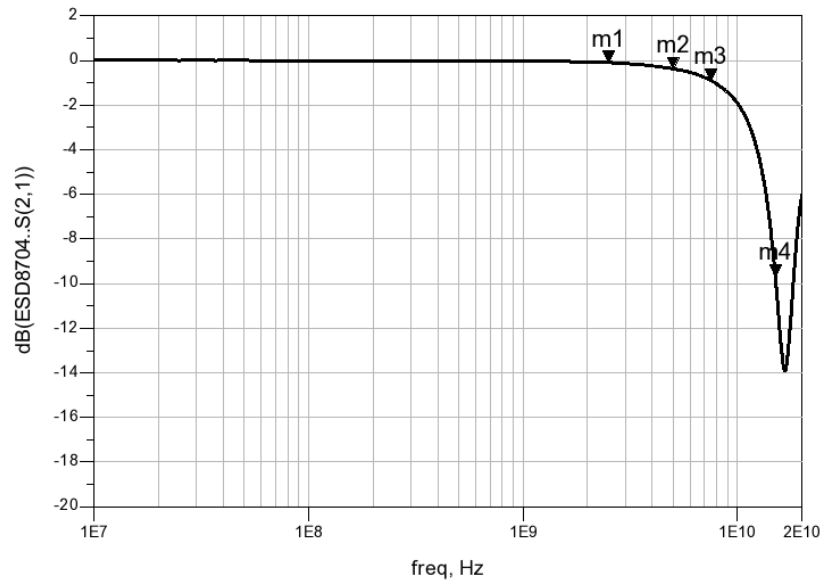


Figure 13. ESD8704 Insertion Loss

| Interface | Data Rate (Gb/s) | Fundamental Frequency (GHz) | 3 <sup>rd</sup> Harmonic Frequency (GHz) | ESD8704 Insertion Loss (dB)                          |
|-----------|------------------|-----------------------------|--|--|
| USB 3.0   | 5                | 2.5 (m1)                    | 7.5 (m3)                                 | m1 = -0.09<br>m3 = -0.89<br>m2 = -0.36<br>m4 = -9.68 |
| USB 3.1   | 10               | 5.0 (m2)                    | 15 (m4)                                  |  |

# ESD8704

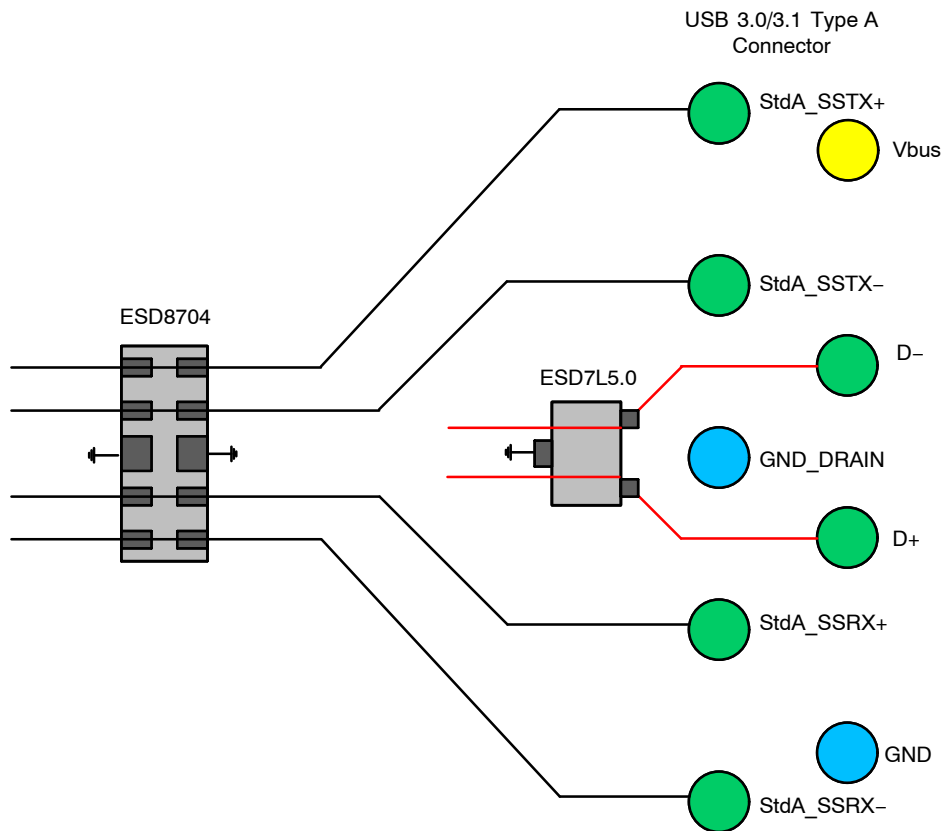


Figure 14. USB 3.0/3.1 Standard Layout Diagram

## PCB Layout Guidelines

Steps must be taken for proper placement and signal trace routing of the ESD protection device in order to ensure the maximum ESD survivability and signal integrity for the application. Such steps are listed below.

- Place the ESD protection device as close as possible to the I/O connector to reduce the ESD path to ground and improve the protection performance.
  - ◆ In USB 3.0 applications, the ESD protection device should be placed between the AC coupling capacitors and the I/O connector on the TX differential lanes as shown in Figure 15. In this configuration, no DC current can flow through the ESD protection device preventing any potential

latch-up condition. For more information on latchup considerations, see below description on Page 8.

- Make sure to use differential design methodology and impedance matching of all high speed signal traces.
  - ◆ Use curved traces when possible to avoid unwanted reflections.
  - ◆ Keep the trace lengths equal between the positive and negative lines of the differential data lanes to avoid common mode noise generation and impedance mismatch.
  - ◆ Place grounds between high speed pairs and keep as much distance between pairs as possible to reduce crosstalk.

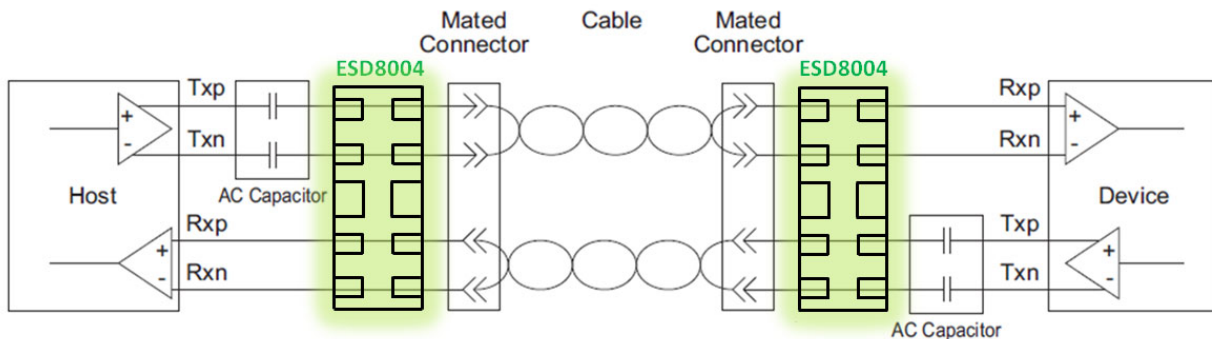
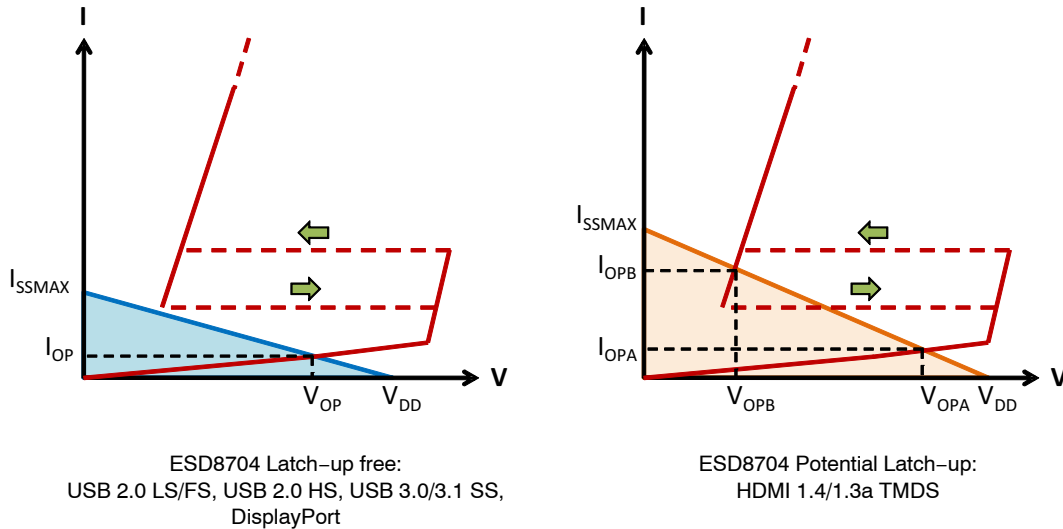


Figure 15. USB 3.0/3.1 Connection Diagram

**Latch-Up Considerations**

onsemi’s 8000 series of ESD protection devices utilize a snap-back, SCR type structure. By using this technology, the potential for a latch-up condition was taken into account by performing load line analyses of common high speed serial interfaces. Example load lines for latch-up free applications and applications with the potential for latch-up are shown below with a generic IV characteristic of a snapback, SCR type structured device overlaid on each. In the latch-up free load line case, the IV characteristic of the snapback protection device intersects the load-line in one unique point ( $V_{OP}$ ,  $I_{OP}$ ). This is the only stable operating point of the circuit and the system is therefore latch-up free.

Please note that for USB 3.0 applications, ESD8704 latch-up free considerations are explained in more detail in the above PCB layout guidelines. In the non-latch up free load line case, the IV characteristic of the snapback protection device intersects the load-line in two points ( $V_{OPA}$ ,  $I_{OPA}$ ) and ( $V_{OPB}$ ,  $I_{OPB}$ ). Therefore in this case, the potential for latch-up exists if the system settles at ( $V_{OPB}$ ,  $I_{OPB}$ ) after a transient. Because of this, ESD8704 should not be used for HDMI applications – ESD8104 or ESD8040 have been designed to be acceptable for HDMI applications without latch-up. Please refer to Application Note AND9116/D for a more in-depth explanation of latch-up considerations using ESD8000 series devices.



**Figure 16. Example Load Lines for Latch-up Free Applications and Applications with the Potential for Latch-up**

**Table 1. SUMMARY OF SCR REQUIREMENTS FOR LATCH-UP FREE APPLICATIONS**

| Application        | VBR (min) (V) | IH (min) (mA) | VH (min) (V) | onsemi ESD8000 Series Recommended PN |
|--------------------|---------------|---------------|--------------|--------------------------------------|
| HDMI 1.4/1.3a TMD5 | 3.465         | 54.78         | 1.0          | ESD8104, ESD8040                     |
| USB 2.0 LS/FS      | 3.301         | 1.76          | 1.0          | ESD8704                              |
| USB 2.0 HS         | 0.482         | N/A           | 1.0          | ESD8704                              |
| USB 3.0/3.1 SS     | 2.800         | N/A           | 1.0          | ESD8704, ESD8006                     |
| DisplayPort        | 3.600         | 25.00         | 1.0          | ESD8704, ESD8006                     |

**DEVICE ORDERING INFORMATION**

| Device          | Marking | Package           | Shipping†          |
|-----------------|---------|-------------------|--------------------|
| ESD8704MUTAG    | 7D      | UDFN10 (Pb-Free)  | 3000 / Tape & Reel |
| SZESD8704MUTAG  | 7D      | UDFN10 (Pb-Free)  | 3000 / Tape & Reel |
| SZESD8704MTWTAG | AAA     | WDFNW10 (Pb-Free) | 3000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# MECHANICAL CASE OUTLINE

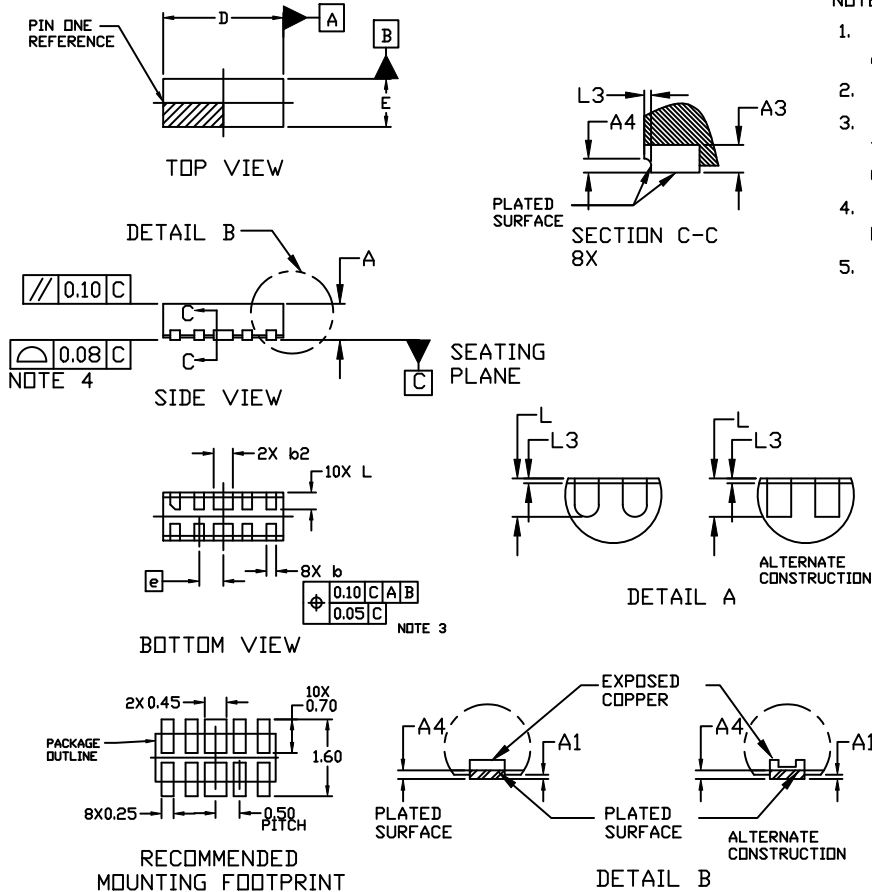
## PACKAGE DIMENSIONS

ON Semiconductor®



### WDFNW10 2.5x1.0, 0.5P CASE 515AH ISSUE B

DATE 03 AUG 2020



**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSION b APPLIES TO PLATED TERMINALS AND IS MEASURED BETWEEN 0.15 AND 0.30MM FROM THE TERMINAL TIP.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.
5. THIS DEVICE CONTAINS WETTABLE FLANK DESIGN FEATURES TO AID IN FILLET FORMATION ON THE LEADS DURING MOUNTING.

| DIM | MILLIMETERS |      |      |
|-----|-------------|------|------|
|     | MIN.        | NOM. | MAX. |
| A   | 0.70        | 0.75 | 0.80 |
| A1  | 0.00        | ---  | 0.05 |
| A3  | 0.20 REF    |      |      |
| A4  | 0.10        | ---  | ---  |
| b   | 0.15        | 0.20 | 0.25 |
| b2  | 0.35        | 0.40 | 0.45 |
| D   | 2.40        | 2.50 | 2.60 |
| E   | 0.90        | 1.00 | 1.10 |
| e   | 0.50 BSC    |      |      |
| L   | 0.30        | 0.35 | 0.40 |
| L3  | ---         | ---  | 0.10 |

### GENERIC MARKING DIAGRAM\*



XX = Specific Device Code  
M = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "μ", may or may not be present. Some products may not follow the Generic Marking.

\* For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SLD1667/D.

|                         |                              |  |
|-------------------------|------------------------------|--|
| <b>DOCUMENT NUMBER:</b> | <b>98AON08744H</b>           | Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |
| <b>DESCRIPTION:</b>     | <b>WDFNW10 2.5x1.0, 0.5P</b> | <b>PAGE 1 OF 1</b>   |

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

# MECHANICAL CASE OUTLINE

## PACKAGE DIMENSIONS

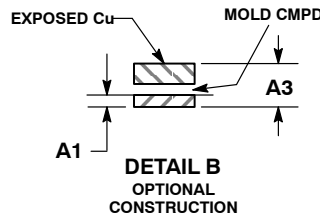
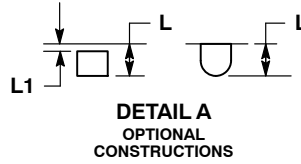
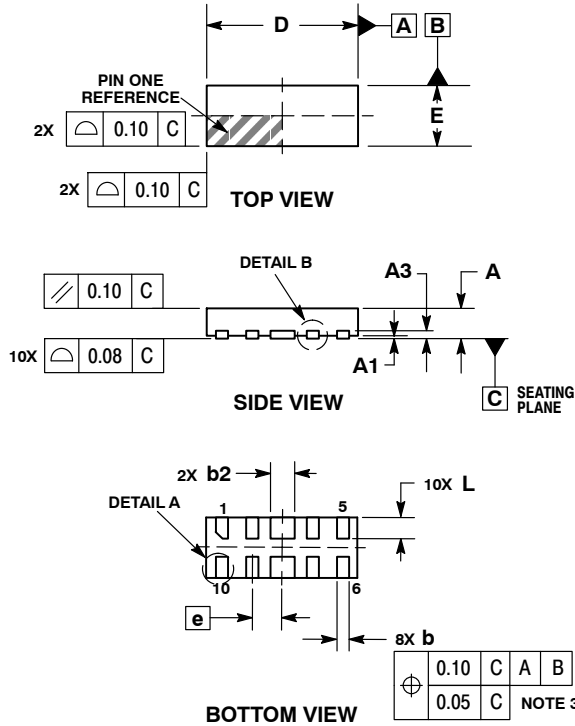
ON Semiconductor®



**UDFN10 2.5x1, 0.5P**  
CASE 517BB-01  
ISSUE O

DATE 17 NOV 2009

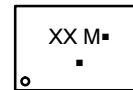
SCALE 4:1



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30mm FROM TERMINAL.

| DIM | MILLIMETERS |      |
|-----|-------------|------|
|     | MIN         | MAX  |
| A   | 0.45        | 0.55 |
| A1  | 0.00        | 0.05 |
| A3  | 0.13 REF    |      |
| b   | 0.15        | 0.25 |
| b2  | 0.35        | 0.45 |
| D   | 2.50 BSC    |      |
| E   | 1.00 BSC    |      |
| e   | 0.50 BSC    |      |
| L   | 0.30        | 0.40 |
| L1  | ---         | 0.05 |

### GENERIC MARKING DIAGRAM\*

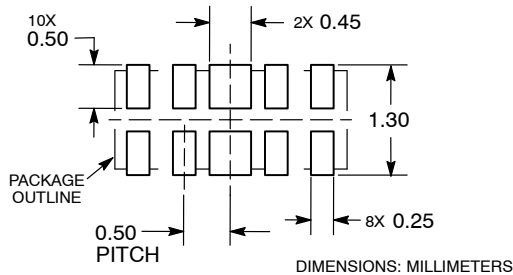


- XXX = Specific Device Code
- M = Date Code
- = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

### RECOMMENDED SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

|                         |                           |  |
|-------------------------|---------------------------|--|
| <b>DOCUMENT NUMBER:</b> | <b>98AON47059E</b>        | Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |
| <b>DESCRIPTION:</b>     | <b>UDFN10 2.5X1, 0.5P</b> | <b>PAGE 1 OF 1</b>   |

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

**onsemi**, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at [www.onsemi.com/site/pdf/Patent-Marking.pdf](http://www.onsemi.com/site/pdf/Patent-Marking.pdf). **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

## ADDITIONAL INFORMATION

### TECHNICAL PUBLICATIONS:

Technical Library: [www.onsemi.com/design/resources/technical-documentation](http://www.onsemi.com/design/resources/technical-documentation)  
onsemi Website: [www.onsemi.com](http://www.onsemi.com)

### ONLINE SUPPORT: [www.onsemi.com/support](http://www.onsemi.com/support)

For additional information, please contact your local Sales Representative at [www.onsemi.com/support/sales](http://www.onsemi.com/support/sales)

## Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

 [View ESD8704MUTAG on WIN SOURCE](#)

 [ON Semiconductor](#) Information

## Optimize Your Supply Chain with WIN SOURCE Solutions

-  Global Sourcing Solution
-  Obsolete Management
-  Cost Control Management
-  Shortage Management
-  Alternative Solution
-  Excess Inventory Management